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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/649,425	08/27/2003	James J. Chambers	TI35714	5169
23494	7590	05/16/2005	EXAMINER	
TEXAS INSTRUMENTS INCORPORATED P O BOX 655474, M/S 3999 DALLAS, TX 75265			SARKAR, ASOK K	
		ART UNIT	PAPER NUMBER	
		2891		

DATE MAILED: 05/16/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

<b>Office Action Summary</b>	<b>Application No.</b>	<b>Applicant(s)</b>	
	10/649,425	CHAMBERS, JAMES J. <i>[Signature]</i>	
	<b>Examiner</b>	<b>Art Unit</b>	
	Asok K. Sarkar	2891	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --  
Period for Reply

**A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.**

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

**Status**

1) Responsive to communication(s) filed on 20 April 2005.  
 2a) This action is **FINAL**.                            2b) This action is non-final.  
 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

**Disposition of Claims**

4) Claim(s) 1,6-14 and 21-26 is/are pending in the application.  
 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.  
 5) Claim(s) 21-26 is/are allowed.  
 6) Claim(s) 1 and 6-14 is/are rejected.  
 7) Claim(s) \_\_\_\_\_ is/are objected to.  
 8) Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

**Application Papers**

9) The specification is objected to by the Examiner.  
 10) The drawing(s) filed on \_\_\_\_\_ is/are: a) accepted or b) objected to by the Examiner.  
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).  
 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

**Priority under 35 U.S.C. § 119**

12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  
 a) All    b) Some \* c) None of:  
 1. Certified copies of the priority documents have been received.  
 2. Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.  
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

\* See the attached detailed Office action for a list of the certified copies not received.

**Attachment(s)**

1) <input type="checkbox"/> Notice of References Cited (PTO-892)	4) <input type="checkbox"/> Interview Summary (PTO-413)
2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Date. _____
3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date _____	5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152)
	6) <input type="checkbox"/> Other: _____

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**DETAILED ACTION**

***Response to Arguments***

1. Applicant's arguments with respect to claims 1 and 6 – 14 have been considered but are moot in view of the new ground(s) of rejection.

***Claim Rejections - 35 USC § 102***

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

3. Claims 1, 6, 7, 9 – 12 and 14 are rejected under 35 U.S.C. 102(e) as being anticipated by Takeuchi, US 2004/008001.

Regarding claim 1, Takeuchi teaches a method of forming dual work function metal gate electrodes in a semiconductor device, comprising:

- forming a gate dielectric 121 over a substrate 101 (see Fig. 5A);
- depositing a mold layer 122 having a first opening 145A therein over said gate dielectric 121 (see Fig. 5B);
- creating a first metal gate electrode by depositing a first metal 111 in said first opening (see Fig. 5C);
- then, etching said mold layer to form a second opening 145 B, and

depositing a second metal 112 in said second opening 145B to form a second metal gate electrode (see Fig. 5C) in paragraphs 108 – 118.

Regarding claim 6, Takeuchi teaches the mold layer is an inorganic material in paragraph 110.

Regarding claim 7, Takeuchi teaches removing the mold layer after depositing the first and second metal with reference to Fig. 6C.

Regarding claim 9, Takeuchi teaches first metal zirconium in paragraph 63.

Regarding claim 10, Takeuchi teaches metals of Pd, Rh, Co and Ni in paragraph 43.

Regarding claim 11, Takeuchi teaches removing excess first and second metals with reference to Figs. 5D and 6B.

Regarding claim 12, Takeuchi teaches removing by CMP in paragraphs 113 and 116.

Regarding claim 14, Takeuchi teaches forming source and drain structures with reference to Fig. 6D.

#### ***Claim Rejections - 35 USC § 103***

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

The factual inquiries set forth in *Graham v. John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

1. Determining the scope and contents of the prior art.
2. Ascertaining the differences between the prior art and the claims at issue.
3. Resolving the level of ordinary skill in the pertinent art.
4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

5. Claim 13 is rejected under 35 U.S.C. 103(a) as being unpatentable over Takeuchi, US 2004/008001.

Takeuchi teaches removing by etching in paragraphs 113 and 116, but fails to teach dry etching.

Therefore, it would have been obvious to one with ordinary skill in the art at the time of the invention to modify Takeuchi and use dry etching since dry etching is a standard practice in semiconductor manufacturing.

6. Claim 8 is rejected under 35 U.S.C. 103(a) as being unpatentable over Takeuchi, US 2004/008001 in view of Liang, US 6,130,123.

Takeuchi fails to teach the work function values for the metal electrodes.

Liang teaches first metal has a work function between about 4 and about 4.2 eV and the second metal has a work and between about 5 and about 5.2 eV in column 1, lines 24 – 33 for the benefit of making CMOS device with enhanced short channel effects in column 1, lines 54 – 57.

Therefore, it would have been obvious to one with ordinary skill in the art at the time of the invention to modify Takeuchi and use metal electrodes of appropriate work

function values for the benefit of making CMOS device with enhanced short channel effects as taught by Liang in column 1, lines 54 – 57.

***Allowable Subject Matter***

7. Claims 21 – 26 are allowed.

8. The following is an examiner's statement of reasons for allowance:

Claims 21 – 26 recite, *inter alia*, a method of forming dual work function metal gate electrodes in a semiconductor device comprising the steps of creating the first electrode by using a first etched mold layer on a substrate and then removing the mold and creating the second electrode using a second mold by etching a second opening and depositing a second metal in that opening. The art of record does not disclose or anticipate the above limitation in combination with other claim elements nor would it be obvious to modify the art of record so as to form a device including the above limitation.

***Conclusion***

1. 9. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any

extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

10. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

11. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Asok K. Sarkar whose telephone number is 571 272 1970. The examiner can normally be reached on Monday - Friday (8 AM- 5 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, William B. Baumeister can be reached on 571 272 1722. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

12. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only.

For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

*Asok Kumar Sarkar*

Asok K. Sarkar

May 10, 2005

Primary Examiner